

# Single photon emitters in exfoliated WSe<sub>2</sub> structures

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Citation Report

#	ARTICLE	IF	CITATIONS
2	Exciton polaritons in two-dimensional dichalcogenide layers placed in a planar microcavity: Tunable interaction between two Bose-Einstein condensates. Physical Review B, 2015, 92, .	1.1	36
3	Single photons for all. Nature Nanotechnology, 2015, 10, 481-481.	15.6	2
4	Excitonic resonances in thin films of $WSe_2$ : from monolayer to bulk material. Nanoscale, 2015, 7, 10421-10429.	2.8	275
5	Voltage-controlled quantum light from an atomically thin semiconductor. Nature Nanotechnology, 2015, 10, 507-511.	15.6	500
6	Two dimensions and one photon. Nature Nanotechnology, 2015, 10, 485-486.	15.6	21
7	Optically active quantum dots in monolayer $WSe_2$ . Nature Nanotechnology, 2015, 10, 491-496.	15.6	648
8	Single quantum emitters in monolayer semiconductors. Nature Nanotechnology, 2015, 10, 497-502.	15.6	749
9	Strain-Induced Spatial and Spectral Isolation of Quantum Emitters in Mono- and Bilayer $WSe_2$ . Nano Letters, 2015, 15, 7567-7573.	4.5	229
10	Control of Light-Matter Interaction in 2D Atomic Crystals Using Microcavities. IEEE Journal of Quantum Electronics, 2015, 51, 1-8.	1.0	5
11	Halide-assisted atmospheric pressure growth of large $WSe_2$ and $WS_2$ monolayer crystals. Applied Materials Today, 2015, 1, 60-66.	2.3	372
12	Spin Coherence and Dephasing of Localized Electrons in Monolayer $MoS_2$ . Nano Letters, 2015, 15, 8250-8254.	4.5	49
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14	Exciton band structure in layered $MoSe_2$ : from a monolayer to the bulk limit. Nanoscale, 2015, 7, 20769-20775.	2.8	163
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